NSN 5961-00-652-8722

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View Online at https://aerobasegroup.com/nsn/5961-00-652-8722 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **End Application:** Simulator, f-111 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 86.1 regulator voltage **Current Rating Per Characteristic:** 580.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Special Features:** Weapon system essential **Test Data Document:** 81349-mil-prf-19500/114 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin **Specification Data:** 81349-mil-prf-19500/114 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization:

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Mil-std (military Standard):

Mil-prf-19500 spec.